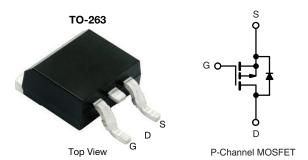


Vishay Siliconix

Automotive P-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	-60				
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0067				
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0088				
I _D (A)	-120				
Configuration	Single				



FEATURES

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- 100 % R_g and UIS tested
- AEC-Q101 qualified ^d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ORDERING INFORMATION					
Package	TO-263				
Lead (Pb)-free and Halogen-free	SQM120P06-07L-GE3				

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	-60	V		
Gate-Source Voltage	V _{GS}	± 20				
Continuous Drois Current a	$T_C = 25 \ ^\circ C \ ^a$		-120			
Continuous Drain Current ^a	T _C = 125 °C	- I _D -	-98			
Continuous Source Current (Diode Conduction) ^a	I _S	-120	A			
Pulsed Drain Current ^b	I _{DM}	-480				
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	-80			
Single Pulse Avalanche Energy		E _{AS}	320	mJ		
Mauineuro Davies Disain ation b	T _C = 25 °C	Pp	375	w		
Maximum Power Dissipation ^b	T _C = 125 °C		125	~~~		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +175	°C			

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)		R _{thJC}	0.4	C/W	

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).

d. Parametric verification ongoing.

S20-0525-Rev. C, 06-Jul-2020

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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static	-	-					I	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$		-60	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$		-2.0	-2.5	v	
Gate-Source Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -60 V	-	-	-1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -60 V, T _J = 125 °C	-	-	-50	μA	
		$V_{GS} = 0 V$	V _{DS} = -60 V, T _J = 175 °C	-	-	-250	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 V$	-120	-	-	Α	
		V _{GS} = -10 V	I _D = -30 A	-	0.0056	0.0067	Ω	
Durain Source On State Desistence a	Р	$V_{GS} = -10 \text{ V}$	I _D = -30 A, T _J = 125 °C	-	-	0.0110		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}$	I _D = -30 A, T _J = 175 °C	-	-	0.0130		
		$V_{GS} = -4.5 V$	I _D = -20 A	-	0.0070	0.0088	1	
Forward Transconductance b	9fs	V _{DS} = -15 V, I _D = -30 A		-	90	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	11 423	14 280		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = -25 V, f = 1 MHz		1034	1295	pF	
Reverse Transfer Capacitance	C _{rss}			-	809	1015	1	
Total Gate Charge ^c	Qg			-	180	270	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = -10 \text{ V}$	$V_{DS} = -30 \text{ V}, I_D = -110 \text{ A}$	-	31	-		
Gate-Drain Charge ^c	Q _{gd}			-	43	-		
Gate Resistance	Rg	f = 1 MHz		1.1	2.27	3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}				15	23		
Rise Time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = \text{-30 V}, R_{\text{L}} = 0.27 \; \Omega \\ I_{\text{D}} \cong \text{-110 A}, V_{\text{GEN}} = \text{-10 V}, R_{\text{g}} = 1 \; \Omega \end{array}$		-	23	35	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	97	146		
Fall Time ^c	t _f			-	32	48		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	-480	Α	
Forward Voltage	V _{SD}	I _F = ·	-	-0.95	-1.5	V		

Notes

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

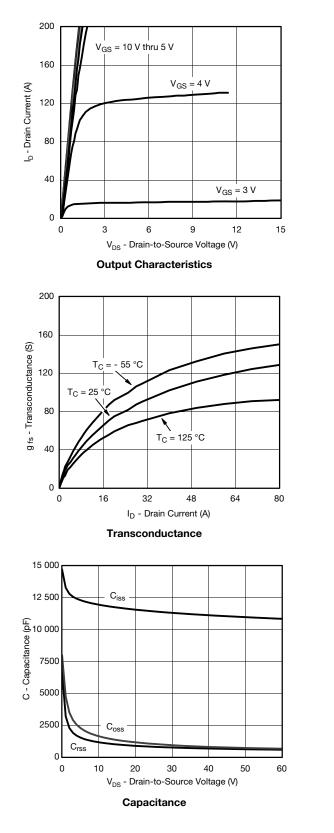
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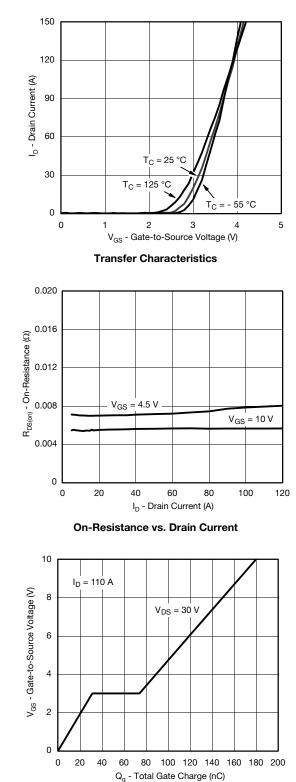


SQM120P06-07L

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





Gate Charge

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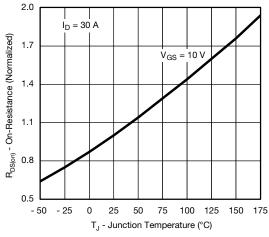
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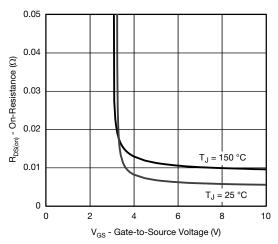
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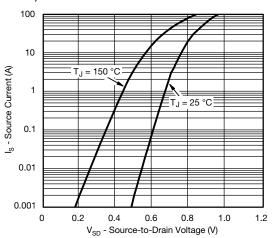
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



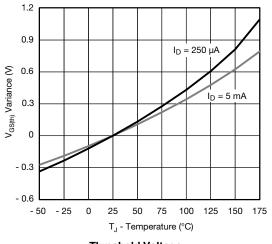
On-Resistance vs. Junction Temperature



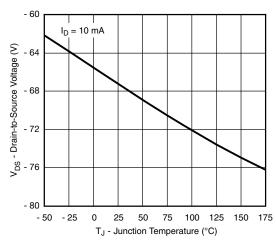
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature

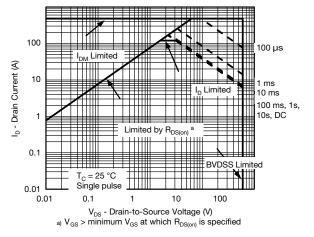
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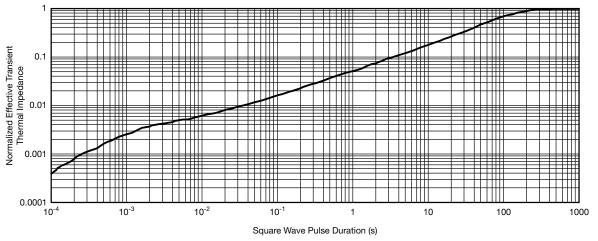


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)







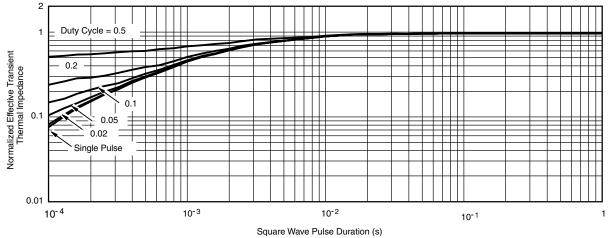
Normalized Thermal Transient Impedance, Junction-to-Ambient

SQM120P06-07L



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)





Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67026.



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TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
A		0.160	0.190	4.064	4.826	
b		0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
E1		0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
e		0.100 BSC		2.54 BSC		
	К	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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